NSN 5962-01-162-4681

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View Online at https://aerobasegroup.com/nsn/5962-01-162-4681 **Body Length:** 1.220 inches **Body Width:** 0.600 inches **Body Height:** 0.095 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5820-01-102-3921 digital message **Features Provided:** Static operation and hermetically sealed and programmable and expandable and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 15.5 volts power source **Time Rating Per Chacteristic:** 850.00 nanoseconds propagation delay time, low to high level output and 850.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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